EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	469	semiconductor and ((gate and (insulat$4 or dielectric)) with (cover$4 near4 (sidewall or side adj wall))) and @ad<"19971020"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/20 21:16
L2	125	semiconductor and ((gate and etch$4 and (insulat$4 or dielectric)) with (cover$4 near4 (sidewall or side adj wall))) and @ad<"19971020"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/20 21:23
S21	911	257/773 and @ad<"19971020"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/20 16:05
S22	845	257/774 and @ad<"19971020"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/20 16:19
S23	244	257/900 and @ad<"19971020"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/20 19:03
S24	260	(257/E23.142).ccls. and @ad<"19971020"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/20 19:12
S25	313	(257/E23.144).ccls. and @ad<"19971020"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/20 19:39
S26	528	(257/E23.145).ccls. and @ad<"19971020"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/20 19:39